74VHC02; 74VHCT02

Quad 2-input NOR gate

Rev. 01 — 13 August 2009

Product data sheet

1. General description

The 74VHC02; 74VHCT02 are high-speed Si-gate CMOS devices and are pin compatible with Low-power Schottky TTL (LSTTL). They are specified in compliance with JEDEC standard No. 7-A.

The 74VHC02; 74VHCT02 provide a quad 2-input NOR function.

2. Features

- Balanced propagation delays
- All inputs have a Schmitt-trigger action
- Inputs accept voltages higher than V_{CC}
- Input levels:
 - ◆ The 74VHC02 operates with CMOS input level
 - ◆ The 74VHCT02 operates with TTL input level
- ESD protection:
 - ◆ HBM JESD22-A114E exceeds 2000 V
 - MM JESD22-A115-A exceeds 200 V
 - ◆ CDM JESD22-C101C exceeds 1000 V
- Multiple package options
- Specified from -40 °C to +85 °C and from -40 °C to +125 °C

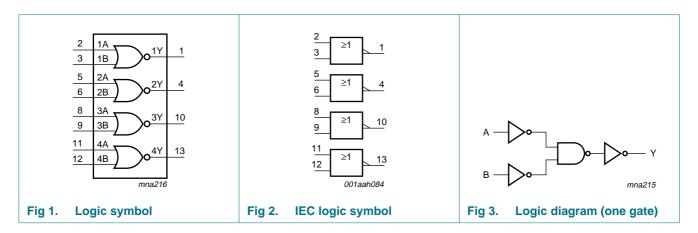
3. Ordering information

Table 1. Ordering information

Type number	Package											
	Temperature range	Name	Description	Version								
74VHC02D	–40 °C to +125 °C	SO14	plastic small outline package; 14 leads;	SOT108-1								
74VHCT02D			body width 3.9 mm									
74VHC02PW	–40 °C to +125 °C	TSSOP14	plastic thin shrink small outline package; 14 leads;	SOT402-1								
74VHCT02PW			body width 4.4 mm									
74VHC02BQ	–40 °C to +125 °C	DHVQFN14	plastic dual in-line compatible thermal enhanced very	SOT762-1								
74VHCT02BQ			thin quad flat package; no leads; 14 terminals; body $2.5 \times 3 \times 0.85$ mm									

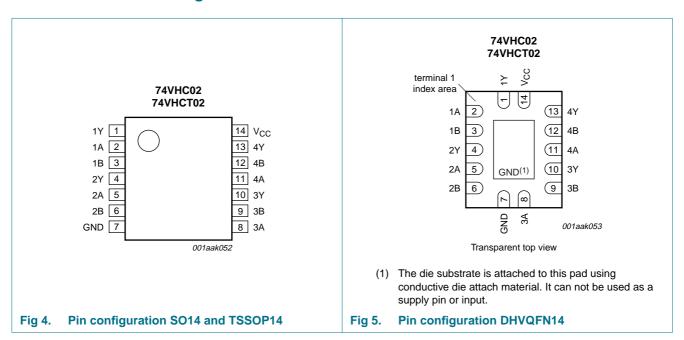


4. Functional diagram



5. Pinning information

5.1 Pinning



5.2 Pin description

Table 2. Pin description

Symbol	Pin	Description
1Y	1	data output
1A	2	data input
1B	3	data input
2Y	4	data output
2A	5	data input
2B	6	data input
GND	7	ground (0 V)
3A	8	data input
3B	9	data input
3Y	10	data output
4A	11	data input
4B	12	data input
4Y	13	data output
V _{CC}	14	supply voltage

Functional description

Function table[1] Table 3.

Input		Output
nA	nB	nY
L	L	Н
X	Н	L
Н	X	L

[1] H = HIGH voltage level;

L = LOW voltage level;

X = don't care.

Product data sheet

7. Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Max	Unit
V_{CC}	supply voltage		-0.5	+7.0	V
V_{I}	input voltage		-0.5	+7.0	V
I_{IK}	input clamping current	$V_{I} < -0.5 V$	<u>[1]</u> –20	-	mA
I _{OK}	output clamping current	$V_O < -0.5 \text{ V or } V_O > V_{CC} + 0.5 \text{ V}$	<u>[1]</u> –20	+20	mA
I _O	output current	$V_O = -0.5 \text{ V to } (V_{CC} + 0.5 \text{ V})$	-25	+25	mA
I_{CC}	supply current		-	+75	mA
I_{GND}	ground current		–75	-	mA
T _{stg}	storage temperature		-65	+150	°C
P _{tot}	total power dissipation	$T_{amb} = -40 ^{\circ}\text{C} \text{ to } +125 ^{\circ}\text{C}$	[2] _	500	mW

^[1] The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

8. Recommended operating conditions

Table 5. Operating conditions

Parameter	Conditions	Min	Тур	Max	Unit
2					
supply voltage		2.0	5.0	5.5	V
input voltage		0	-	5.5	V
output voltage		0	-	V_{CC}	V
ambient temperature		-40	+25	+125	°C
input transition rise and fall rate	$V_{CC} = 3.0 \text{ V to } 3.6 \text{ V}$	-	-	100	ns/V
	$V_{CC} = 4.5 \text{ V to } 5.5 \text{ V}$	-	-	20	ns/V
02					
supply voltage		4.5	5.0	5.5	V
input voltage		0	-	5.5	V
output voltage		0	-	V_{CC}	V
ambient temperature		-40	+25	+125	°C
input transition rise and fall rate	$V_{CC} = 4.5 \text{ V to } 5.5 \text{ V}$	-	-	20	ns/V
	input voltage output voltage ambient temperature input transition rise and fall rate 02 supply voltage input voltage output voltage ambient temperature	supply voltage input voltage output voltage ambient temperature input transition rise and fall rate V _{CC} = 3.0 V to 3.6 V V _{CC} = 4.5 V to 5.5 V supply voltage input voltage output voltage ambient temperature	supply voltage 2.0 input voltage 0 0 output voltage 0 ambient temperature -40 input transition rise and fall rate $V_{CC} = 3.0 \text{ V to } 3.6 \text{ V} - V_{CC} = 4.5 \text{ V to } 5.5 \text{ V}$ - 202 supply voltage 4.5 input voltage 0 output voltage 0 ambient temperature 0 ambient temperature -40	supply voltage $2.0 5.0$ input voltage $0 -2.0$ ambient temperature $-40 +25$ input transition rise and fall rate $V_{CC} = 3.0 V$ to $3.6 V$ -2.0 -2.0 -2.0 -2.0 -2.0 -2.0 -2.0 -2.0 -2.0 -2.0 -2.0 -2.0 -2.0 -2.0 input voltage $-2.0 -2.0$ -2.0 -2.0 input voltage $-2.0 -2.0$ -2.0 -2.0 ambient temperature $-2.0 -2.0$ -2.0 ambient temperature $-2.0 -2.0$ -2.0 -2.0 ambient temperature $-2.0 -2.0$ -2.0	2.0 5.0 5.5 input voltage 0 - 5.5 output voltage 0 - V_{CC} ambient temperature -40 +25 +125 input transition rise and fall rate $V_{CC} = 3.0 \text{ V to } 3.6 \text{ V}$ - - 100 $V_{CC} = 4.5 \text{ V to } 5.5 \text{ V}$ - - 20 3upply voltage 4.5 5.0 5.5 input voltage 0 - 5.5 output voltage 0 - V_{CC} ambient temperature -40 +25 +125

^[2] For SO14 packages: above 70 °C the value of P_{tot} derates linearly at 8 mW/K.
For TSSOP14 packages: above 60 °C the value of P_{tot} derates linearly at 5.5 mW/K.
For DHVQFN14 packages: above 60 °C the value of P_{tot} derates linearly at 4.5 mW/K.

9. Static characteristics

Table 6. Static characteristics

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions		25 °C		-40 °C	to +85 °C	–40 °C t	o +125 °C	Unit
			Min	Тур	Max	Min	Max	Min	Max	
74VHC0	2					'			'	
V_{IH}	HIGH-level	V _{CC} = 2.0 V	1.5	-	-	1.5	-	1.5	-	V
	input voltage	V _{CC} = 3.0 V	2.1	-	-	2.1	-	2.1	-	V
		V _{CC} = 5.5 V	3.85	-	-	3.85	-	3.85	-	V
V_{IL}	LOW-level	V _{CC} = 2.0 V	-	-	0.5	-	0.5	-	0.5	V
	input voltage	V _{CC} = 3.0 V	-	-	0.9	-	0.9	-	0.9	V
		V _{CC} = 5.5 V	-	-	1.65	-	1.65	-	1.65	V
V _{OH}	HIGH-level	$V_I = V_{IH}$ or V_{IL}								
	output voltage	$I_O = -50 \mu A; V_{CC} = 2.0 V$	1.9	2.0	-	1.9	-	1.9	-	V
		$I_O = -50 \mu A; V_{CC} = 3.0 V$	2.9	3.0	-	2.9	-	2.9	-	V
		$I_O = -50 \mu A$; $V_{CC} = 4.5 V$	4.4	4.5	-	4.4	-	4.4	-	V
		$I_O = -4.0 \text{ mA}; V_{CC} = 3.0 \text{ V}$	2.58	-	-	2.48	-	2.40	-	V
		$I_O = -8.0 \text{ mA}; V_{CC} = 4.5 \text{ V}$	3.94	-	-	3.80	-	3.70	-	V
V_{OL}	LOW-level	$V_I = V_{IH}$ or V_{IL}								
	output voltage	$I_O = 50 \mu A; V_{CC} = 2.0 V$	-	0	0.1	-	0.1	-	0.1	V
		$I_O = 50 \mu A; V_{CC} = 3.0 V$	-	0	0.1	-	0.1	-	0.1	V
		$I_O = 50 \mu A; V_{CC} = 4.5 V$	-	0	0.1	-	0.1	-	0.1	V
		$I_O = 4.0 \text{ mA}; V_{CC} = 3.0 \text{ V}$	-	-	0.36	-	0.44	-	0.55	V
		$I_O = 8.0 \text{ mA}; V_{CC} = 4.5 \text{ V}$	-	-	0.36	-	0.44	-	0.55	V
II	input leakage current	$V_I = 5.5 \text{ V or GND};$ $V_{CC} = 0 \text{ V to } 5.5 \text{ V}$	-	-	0.1	-	1.0	-	2.0	μΑ
I _{CC}	supply current	$V_I = V_{CC}$ or GND; $I_O = 0$ A; $V_{CC} = 5.5 \text{ V}$	-	-	2.0	-	20	-	40	μΑ
C _I	input capacitance		-	3	10	-	10	-	10	pF

 Table 6.
 Static characteristics ...continued

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions		25 °C		-40 °C 1	to +85 °C	–40 °C t	o +125 °C	Unit
			Min	Тур	Max	Min	Max	Min	Max	
74VHCT	02								'	
V_{IH}	HIGH-level input voltage	$V_{CC} = 4.5 \text{ V to } 5.5 \text{ V}$	2.0	-	-	2.0	-	2.0	-	V
V_{IL}	LOW-level input voltage	$V_{CC} = 4.5 \text{ V to } 5.5 \text{ V}$	-	-	8.0	-	0.8	-	0.8	V
V_{OH}	HIGH-level	$V_I = V_{IH}$ or V_{IL} ; $V_{CC} = 4.5 \text{ V}$								
	output voltage	$I_O = -50 \mu A$	4.4	4.5	-	4.4	-	4.4	-	V
		$I_{O} = -8.0 \text{ mA}$	3.94	-	-	3.80	-	3.70	-	V
~-	LOW-level	$V_I = V_{IH}$ or V_{IL} ; $V_{CC} = 4.5 \text{ V}$								
	output voltage	$I_O = 50 \mu A$	-	0	0.1	-	0.1	-	0.1	V
		$I_{O} = 8.0 \text{ mA}$	-	-	0.36	-	0.44	-	0.55	V
II	input leakage current	$V_I = 5.5 \text{ V or GND};$ $V_{CC} = 0 \text{ V to 5.5 V}$	-	-	0.1	-	1.0	-	2.0	μΑ
I _{CC}	supply current	$V_I = V_{CC}$ or GND; $I_O = 0$ A; $V_{CC} = 5.5 \text{ V}$	-	-	2.0	-	20	-	40	μΑ
ΔI_{CC}	additional supply current	per input pin; $\begin{aligned} &V_I = V_{CC} - 2.1 \text{ V;} \\ &\text{other pins at } V_{CC} \text{ or GND;} \\ &I_O = 0 \text{ A; } V_{CC} = 4.5 \text{ V to } 5.5 \text{ V} \end{aligned}$	-	-	1.35	-	1.5	-	1.5	mA
C _I	input capacitance		-	3	10	-	10	-	10	pF

10. Dynamic characteristics

Table 7. Dynamic characteristics

Voltages are referenced to GND (ground = 0 V); for test circuit see Figure 7.

Symbol	Parameter	Conditions		25 °C		-40 °C	to +85 °C	-40 °C t	o +125 °C	Unit
				າ Typ <mark>[1]</mark>	Max	Min	Max	Min	Max	
74VHC0	2	'	'	· ·			'	'	•	
t _{pd}	propagation	nA, nB to nY; see Figure 6	[2]							
	delay	$V_{CC} = 3.0 \text{ V to } 3.6 \text{ V}$								
		C _L = 15 pF	-	3.9	7.9	1.0	9.5	1.0	10.0	ns
		$C_L = 50 pF$	-	5.5	11.4	1.0	13	1.0	14.5	ns
		$V_{CC} = 4.5 \text{ V to } 5.5 \text{ V}$								
		C _L = 15 pF	-	2.9	5.5	1.0	6.5	1.0	7.0	ns
		$C_L = 50 pF$		4.2	7.5	1.0	8.5	1.0	9.5	ns
C_{PD}	power dissipation capacitance	C_L = 50 pF; f_i = 1 MHz; V_I = GND to V_{CC}	[3] _	7.0	-	-	-	-	-	pF

 Table 7.
 Dynamic characteristics ...continued

Voltages are referenced to GND (ground = 0 V); for test circuit see Figure 7.

Symbol	Parameter	Conditions		25 °C			-40 °C 1	to +85 °C	-40 °C t	Unit	
				Min	Typ[1]	Max	Min	Max	Min	Max	
74VHCT	02; V _{CC} = 4.5	V to 5.5 V							'		
t _{pd}	propagation	nA, nB to nY; see Figure 6	[2]								
·	delay	C _L = 15 pF		-	3.8	5.5	1.0	6.5	1.0	7.0	ns
		$C_L = 50 pF$		-	5.1	7.5	1.0	8.5	1.0	9.5	ns
C _{PD}	power dissipation capacitance	C_L = 50 pF; f_i = 1 MHz; V_I = GND to V_{CC}	[3]	-	8.0	-	-	-	-	-	pF

- [1] Typical values are measured at nominal supply voltage ($V_{CC} = 3.3 \text{ V}$ and $V_{CC} = 5.0 \text{ V}$).
- [2] t_{pd} is the same as t_{PLH} and t_{PHL} .
- [3] C_{PD} is used to determine the dynamic power dissipation (P_D in μW).

 $P_D = C_{PD} \times V_{CC}^2 \times f_i \times N + \Sigma (C_L \times V_{CC}^2 \times f_o)$ where:

 f_i = input frequency in MHz;

f_o = output frequency in MHz;

C_L = output load capacitance in pF;

V_{CC} = supply voltage in V;

N = number of inputs switching;

 $\Sigma(C_L \times V_{CC}^2 \times f_o)$ = sum of the outputs.

11. Waveforms

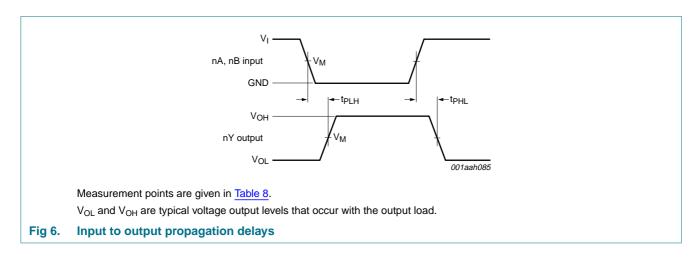
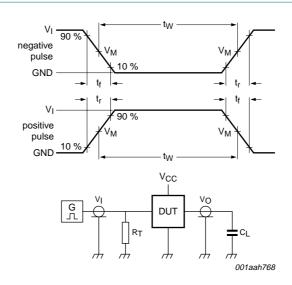


Table 8. Measurement points

Туре	Input	Output
	V _M	V _M
74VHC02	0.5V _{CC}	0.5V _{CC}
74VHCT02	1.5 V	0.5V _{CC}



Test data is given in Table 9.

Definitions test circuit:

 R_T = termination resistance should be equal to output impedance Z_o of the pulse generator.

 C_L = load capacitance including jig and probe capacitance.

Fig 7. Load circuitry for measuring switching times

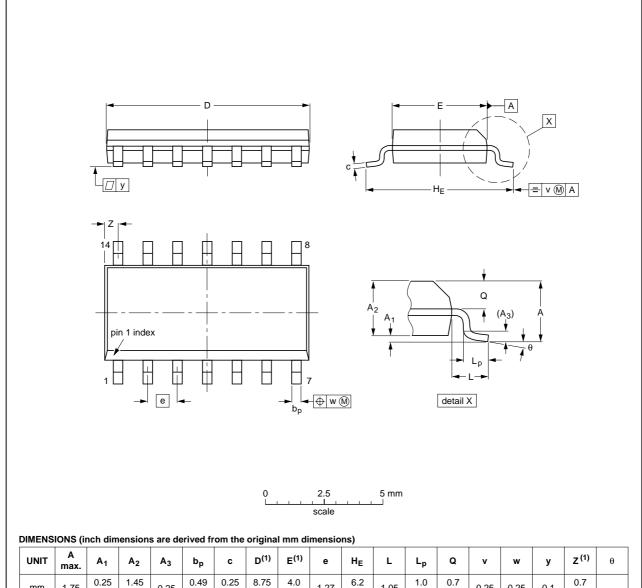
Table 9. Test data

Туре	Input		Load	Test
	VI	t _r , t _f	CL	
74VHC02	V _{CC}	≤ 3.0 ns	15 pF, 50 pF	t _{PLH} , t _{PHL}
74VHCT02	3.0 V	≤ 3.0 ns	15 pF, 50 pF	t _{PLH} , t _{PHL}

12. Package outline

SO14: plastic small outline package; 14 leads; body width 3.9 mm

SOT108-1



UNIT	A max.	A ₁	A ₂	A ₃	bp	С	D ⁽¹⁾	E ⁽¹⁾	е	HE	L	Lp	Q	v	w	у	z ⁽¹⁾	θ
mm	1.75	0.25 0.10	1.45 1.25	0.25	0.49 0.36	0.25 0.19	8.75 8.55	4.0 3.8	1.27	6.2 5.8	1.05	1.0 0.4	0.7 0.6	0.25	0.25	0.1	0.7 0.3	8°
inches	0.069	0.010 0.004	0.057 0.049	0.01		0.0100 0.0075		0.16 0.15	0.05	0.244 0.228	0.041	0.039 0.016	0.028 0.024	0.01	0.01	0.004	0.028 0.012	0°

Note

Product data sheet

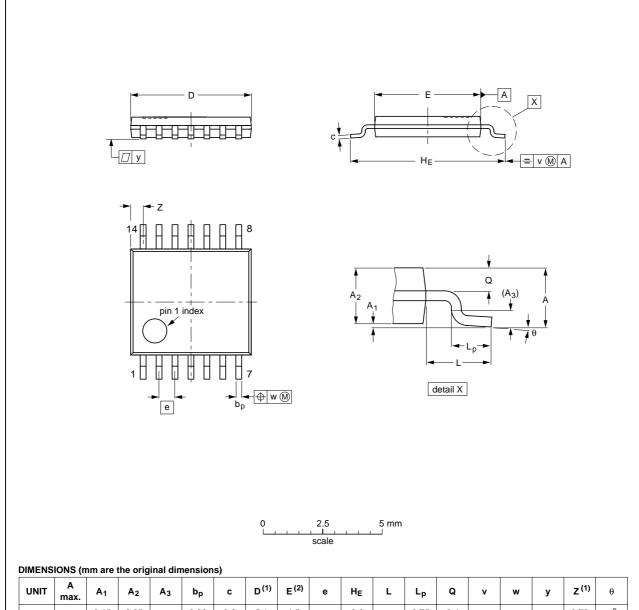
1. Plastic or metal protrusions of 0.15 mm (0.006 inch) maximum per side are not included.

OUTLINE		REFER	EUROPEAN	ISSUE DATE		
VERSION	IEC	JEDEC	JEITA		PROJECTION	1330E DATE
SOT108-1	076E06	MS-012				99-12-27 03-02-19

Fig 8. Package outline SOT108-1 (SO14)

TSSOP14: plastic thin shrink small outline package; 14 leads; body width 4.4 mm

SOT402-1



UNIT	A max.	A ₁	A ₂	А3	bp	С	D ⁽¹⁾	E ⁽²⁾	е	HE	L	Lp	Q	v	w	у	z ⁽¹⁾	θ
mm	1.1	0.15 0.05	0.95 0.80	0.25	0.30 0.19	0.2 0.1	5.1 4.9	4.5 4.3	0.65	6.6 6.2	1	0.75 0.50	0.4 0.3	0.2	0.13	0.1	0.72 0.38	8° 0°

Notes

Product data sheet

- 1. Plastic or metal protrusions of 0.15 mm maximum per side are not included.
- 2. Plastic interlead protrusions of 0.25 mm maximum per side are not included.

OUTLINE		REFER	EUROPEAN	ISSUE DATE		
VERSION	IEC	JEDEC	JEITA		PROJECTION	ISSUE DATE
SOT402-1		MO-153				99-12-27 03-02-18

Fig 9. Package outline SOT402-1 (TSSOP14)

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DHVQFN14: plastic dual in-line compatible thermal enhanced very thin quad flat package; no leads; SOT762-1 14 terminals; body 2.5 x 3 x 0.85 mm

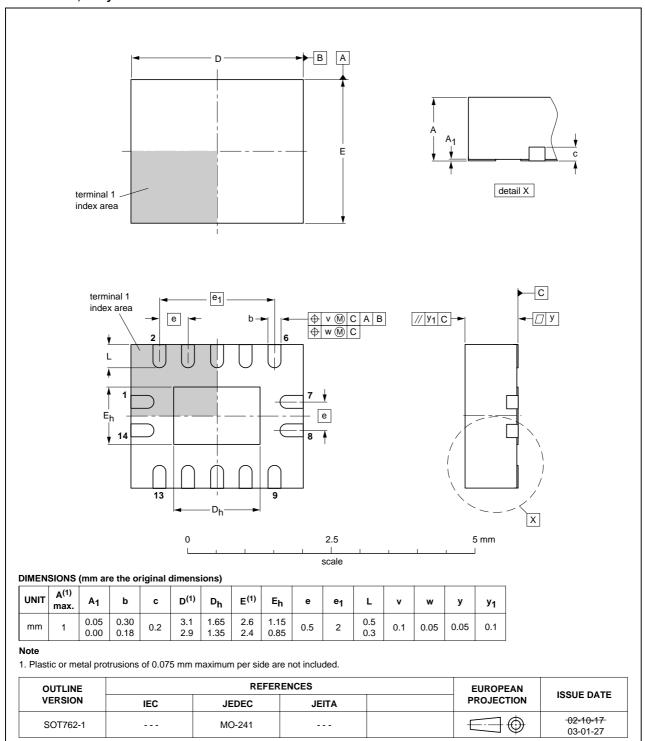


Fig 10. Package outline SOT762-1 (DHVQFN14)

Product data sheet

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13. Abbreviations

Table 10. Abbreviations

Acronym	Description
CDM	Charged Device Model
CMOS	Complementary Metal-Oxide Semiconductor
DUT	Device Under Test
ESD	ElectroStatic Discharge
HBM	Human Body Model
LSTTL	Low-power Schottky Transistor-Transistor Logic
MM	Machine Model

14. Revision history

Table 11. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
74VHC_VHCT02_1	20090813	Product data sheet	-	-

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Product data sheet

15. Legal information

15.1 Data sheet status

Document status[1][2]	Product status[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- [1] Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions"
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